

20V N-Channel Enhancement Mode MOSFET

Current

7.3 A

Features

Voltage

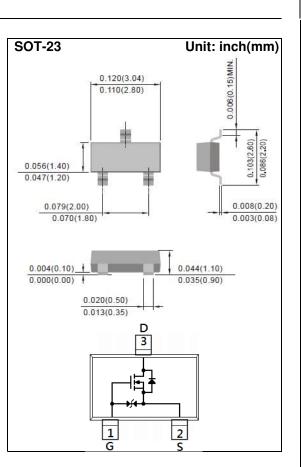
- $R_{DS(ON)}$, V_{GS} @4.5V, I_D @5A<15.5m Ω
- R_{DS(ON)}, V_{GS}@2.5V, I_D@4.5A<17.5mΩ

20 V

- R_{DS(ON)}, V_{GS}@1.8V, I_D@4A<22.5mΩ
- Advanced Trench Process Technology
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|---|----------------------|----------------------------------|---------|-------|--|
| Drain-Source Voltage | | V _{DS} | 20 | | |
| Gate-Source Voltage | V _{GS} | <u>+</u> 10 | V | | |
| Continuous Drain Current (Note 4) | | I _D | 7.3 | A | |
| Pulsed Drain Current (Note 1) | | I _{DM} | 29.2 | | |
| Power Dissipation | T _A =25°C | | 1.25 | W | |
| | Derate above 25°C | P _D | 10 | mW/°C | |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~150 | °C | |
| Typical Thermal Resistance - Junction to Ambient ^(Note 3,4) | | R _{θJA} | 100 | °C/W | |



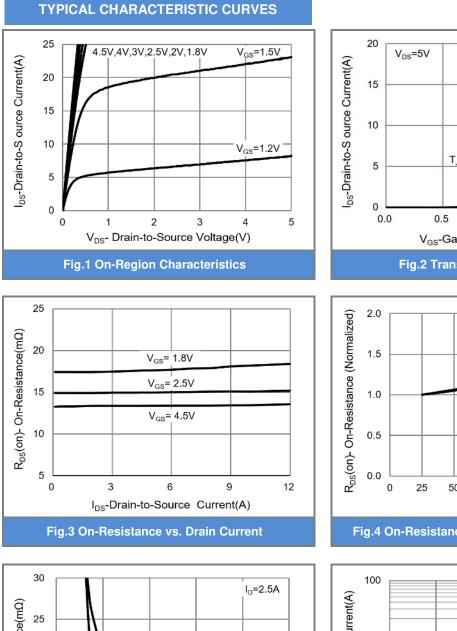
Electrical Characteristics (T_A=25°C unless otherwise noted)

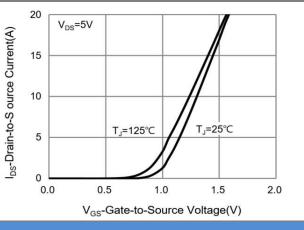
| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|--|---------------------|---|------|------|-------------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 20 | - | - | N/ |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}, I_{D}=250 uA$ | 0.3 | 0.6 | 1 | V |
| Drain-Source On-State Resistance | R _{DS(on)} | V_{GS} =4.5V, I _D =5A | - | 13 | 15.5 | mΩ |
| | | V _{GS} =2.5V, I _D =4.5A | - | 14.5 | 17.5 | |
| | | V_{GS} =1.8V, I_{D} =4A | - | 17 | 22.5 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =20V, V_{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 10V, V _{DS} =0V | - | - | <u>+</u> 10 | uA |
| Dynamic (Note 5) | | | | | | |
| Total Gate Charge | Qg | | - | 16 | - | nC |
| Gate-Source Charge | Q_{gs} | V_{DS} =10V, I _D =9A, V _{GS} =4.5V ^(Note 2,3) | - | 1.3 | - | |
| Gate-Drain Charge | Q_gd | | - | 1.6 | - | |
| Input Capacitance | Ciss | | - | 1177 | - | pF |
| Output Capacitance | Coss | $V_{DS}=10V, V_{GS}=0V,$ | - | 157 | - | |
| Reverse Transfer Capacitance | Crss | f=1MHZ | - | 134 | - | |
| Turn-On Delay Time | td _(on) | | - | 16 | - | ns |
| Turn-On Rise Time | tr | $V_{DD}=10V, I_{D}=1A,$ $V_{GS}=4.5V,$ $R_{G}=25\Omega^{(Note 2,3)}$ | - | 25 | - | |
| Turn-Off Delay Time | td _(off) | | - | 124 | - | |
| Turn-Off Fall Time | tf | $R_{G}=25\Omega$ | - | 101 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I _S | | - | - | 1.5 | А |
| Diode Forward Voltage | V _{SD} | I _S =1A, V _{GS} =0V | - | 0.73 | 1 | V |

NOTES:

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 5. Guaranteed by design, not subject to production testing.









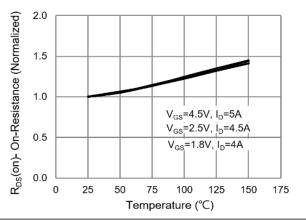


Fig.4 On-Resistance vs. Junction temperature

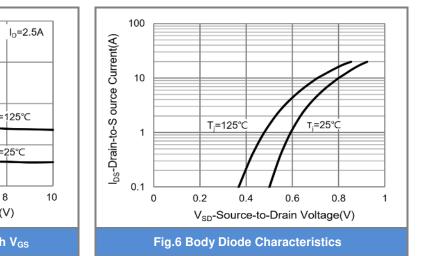
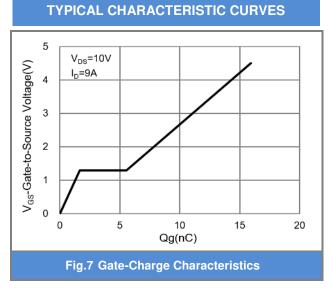


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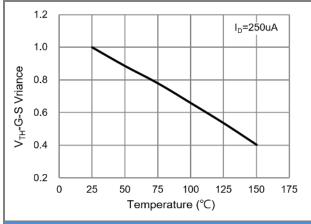
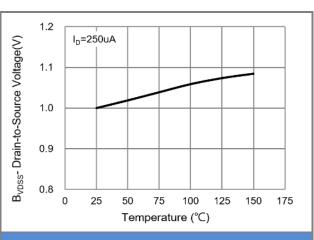


Fig.9 Threshold Voltage Variation with Temperature





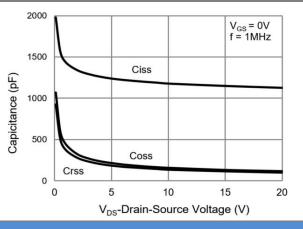


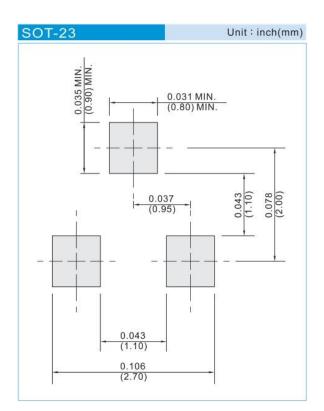
Fig.10 Capacitance vs. Drain-Source Voltage



Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|----------------------|--------------|------------------|---------|--------------|
| PJA3456E_R1_00001 | SOT-23 | 3K pcs / 7" reel | 56E | Halogen free |

Mounting Pad Layout





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